TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXH162374FT

Low-Voltage 16-Bit D-Type Flip-Flop with Bushold

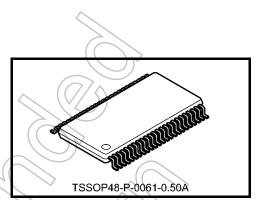
The TC74VCXH162374FT is a high-performance CMOS 16-bit D-type flip-flop. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This 16-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input (\overline{OE}) which are common to each byte. It can be used as two 8-bit flip-flops or one 16-bit flip-flop. When the \overline{OE} input is high, the outputs are in a high impedance state.

The $26\text{-}\Omega$ series resistor helps reducing output overshoot and undershoot without external resistor.

The D data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

Features

- 26-Ω series resistors on outputs
- Low-voltage operation: VCC = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation: $t_{pd} = 3.4 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$

$$t_{pd} = 4.8 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$$

:
$$t_{pd} = 6.0 \text{ ns (max) (V}_{CC} = 1.8 \text{ V)}$$

• Output current: $I_{OH}/I_{OL} = \pm 12 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$

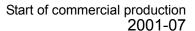
:
$$I_{OH}/I_{OL} = \pm 8 \text{ mA (min)} (V_{CC} = 2.3 \text{ V})$$

:
$$I_{OH}/I_{OL} = \pm 4 \text{ mA (min) (V}_{CC} = 1.8 \text{ V)}$$

- Latch-up performance: -300 mA
- ESD performance: Machine model ≥ ±200 V

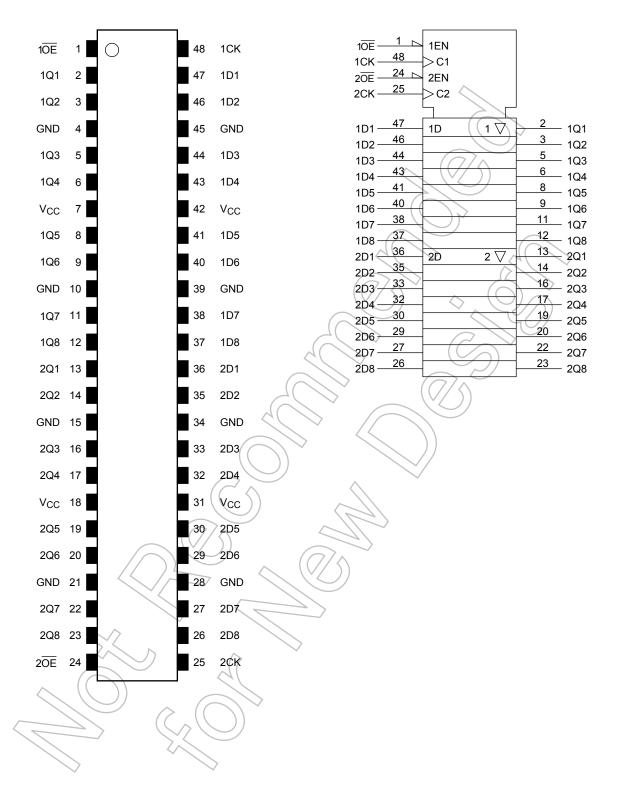
Human body model ≥ ±2000 V

- Package: TSSOP
- 3.6-V tolerant function and power-down protection control inputs and outputs



Pin Assignment (top view)

IEC Logic Symbol



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Truth Table

	Outputs		
1 OE	1CK	1D1-1D8	1Q1-1Q8
Н	X	X	Z
L	\rightarrow	Х	Qn
L		L	L
L	\Box	Н	Н

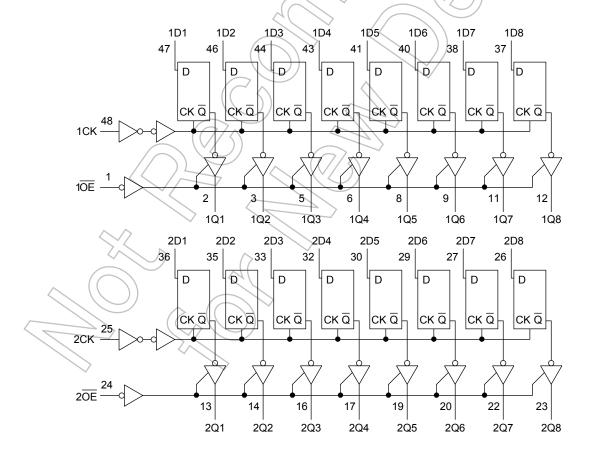
	Outputs		
2OE	2CK	2D1-2D8	2Q1-2Q8
Н	Х	Х	Z
L	\rightarrow	Х	Qn
L		L	L
L		Н	Н

X: Don't care

Z: High impedance

Qn: No change

System Diagram



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Absolute Maximum Ratings (Note 1)

Characteris	Characteristics		Rating	Unit
Power supply voltage		V_{CC}	-0.5 to 4.6	V
DC input voltage	(OE, CK)	V _{IN}	-0.5 to 4.6	V
DC Input voltage	(An)	VIN	-0.5 to V _{CC} + 0.5	V
DC output voltage		Vоит	-0.5 to 4.6 (Note 2)	V
DC output voltage		VOUT	-0.5 to V _{CC} + 0.5 (Note 3)	
Input diode current		l _{IK}	-50	mA
Output diode current		I _{OK}	±50 (Note 4)	(mA)
Output current	Output current		±50	mA
Power dissipation		P _D	400	mW
DC V _{CC} /ground current per supply pin		I _{CC} /I _{GND}	±100	> mA
Storage temperature		T _{stg}	-65 to 150	°C <

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc



Operating Ranges (Note 1) (Note 2)

Characteris	tics	Symbol	Rating	Unit
Device complex relations		V _{CC}	1.8 to 3.6	V
Power supply voltage		v CC	1.2 to 3.6 (Note 3)	V
Input voltage	(OE, CK)	\/	-0.3 to 3.6	V
input voitage	(An)	V _{IN}	0 to V _{CC}	V
Output voltage		\/a	0 to 3.6 (Note 4)	V
Output voltage		V _{OUT}	0 to V _{CC} (Note 5)	v (C)
			±12 (Note 6)	
Output current	Output current		±8 (Note 7)	mA
			±4 (Note 8)	(\bigcirc)
Operating temperature		T _{opr}	-40 to 85	်င
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V

- Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.
- Note 2: Floating or unused control inputs must be held high or low.
- Note 3: Data retention
- Note 4: OFF state
- Note 5: High or low state
- Note 6: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
- Note 7: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
- Note 8: $V_{CC} = 1.8 \text{ V}$
- Note 9: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

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Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characteris	stics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
	H-level	V _{IH}	_	_	2.7 to 3.6	2.0	_	.,
Input voltage	L-level	V _{IL}	_	_	2.7 to 3.6	_	8.0	V
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -6 mA	//2.7	2.2	_	
				$I_{OH} = -8 \text{ mA}$	3.0	2.4	_	
Output voltage				I _{OH} = -12 mA	3.0	2.2	_	V
				$I_{OL} = 100 \mu\text{A}$	2.7 to 3.6		0.2	
	L-level	Vol	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 6 mA	2.7	H)	0.4	
	L-IEVEI	VOL	AIM - AIH OL AIF	I _{OL} = 8 mA	3.0	_/	0.5	
				I _{OL} = 12 mA	3.0)	0.8	
Input leakage	(OE, CK)	1	V _{IN} = 0 to 3.6 V		2.7 to 3.6		±5.0	^
current	(An)	I _{IN}	V _{IN} = V _{CC} or GND		2.7 to 3.6	(±5.0	μА
Bushold input minim	um drive	1	V _{IN} = 0.8 V		(3.0)	75	_	^
hold current		I _I (HOLD)	V _{IN} = 2.0 V		3.0	-75	_	μА
Bushold input over-o	drive current			(Note 1)	3.6	_	450	^
to change state			4()	(Note 2)	3.6	_	-450	μΑ
3-state output OFF s	state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.7 to 3.6	_	±10.0	μА
Power-off leakage c	urrent	loff	V _{OUT} = 0 to 3.6 V		0	_	10.0	μА
Quiagant gunstress	rrant	Icc	V _{IN} = V _{CC} or GND		2.7 to 3.6	_	20.0	
Quiescent supply cu	Quiescent supply current		V _{CC} ≤ V _{OUT} ≤ 3.6 V	(Note 3)	2.7 to 3.6	_	±20.0	μΑ
Increase in I _{CC} per i	nput	Δlcc	V _{IH} = V _{CC} - 0.6 V	3)	2.7 to 3.6	_	750	μΑ

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

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Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteris	stics	Symbol	Test Co	ondition	V _{CC} (V)	Min	Max	Unit
	H-level	V _{IH}	_		2.3 to 2.7	1.6		
Input voltage	L-level	V _{IL}	_		2.3 to 2.7	_	0.7	V
				I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	_	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{II}	I _{OH} = -4 mA	2.3	2.0	_	
		011		I _{OH} = -6 mA	2.3	1.8	_	
Output voltage				I _{OH} = -8 mA	(2.3)	1.7	_	V
				I _{OL} = 100 μA	2.3 to 2.7		0.2	
	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 6 mA	2.3		0.4	
				$I_{OL} = 8 \text{ mA}$	2.3		0.6	
Input leakage	(OE, CK)	I _{IN}	$V_{IN} = 0$ to 3.6 V		2.3 to 2.7	7	±5.0	μА
current	(An)	NII	$V_{IN} = V_{CC}$ or GND		2.3 to 2.7		>±5.0	μΛ
Bushold input minim	um drive	li (iloi p)	$V_{IN} = 0.7 V$		2.3	45) —	μΑ
hold current		l (HOLD)	V _{IN} = 1.6 V		2.3	45	_	μΛ
Bushold input over-o	drive current	li (OD)		(Note 1)	2.7	_	300	μΑ
to change state		l _{I (OD)}		(Note 2)	2.7	_	-300	μΛ
3-state output OFF	state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.3 to 2.7		±10.0	μΑ
Power-off leakage c	urrent	I _{OFF}	V _{OUT} = 0 to 3.6 V		0	_	10.0	μΑ
Quiocoopt quarky av	rront	laa	V _{IN} = V _{CC} or GND		2.3 to 2.7	_	20.0	
Quiescent supply cu	inent	Icc	V _{CC} ≤ V _{OUT} ≤ 3.6 V	(Note 3)	2.3 to 2.7	_	±20.0	μА

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

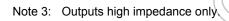


DC Characteristics (Ta = -40 to 85° C, $1.8 \text{ V} \leq \text{V}_{\text{CC}} < 2.3 \text{ V})$

Characteri	stics	Symbol	Test Co	ondition	V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	_	_	1.8 to 2.3	0.7 × V _{CC}	_	V
input voltage	L-level	V _{IL}	_	_	1.8 to 2.3	_	0.2 × V _{CC}	V
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.8	VCC 0.2	_	
Output voltage				I _{OH} = -4 mA	71,8	1.4	_	V
	L-level	VOI	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8		0.2	
	L-level	VOL	AIN = AIH OI AIL	I _{OL} = 4 mA	1.8		0.3	
Input leakage	(OE , CK)	I _{IN}	$V_{IN} = 0$ to 3.6 V		1.8		±5.0	μА
current	(An)	IN	$V_{IN} = V_{CC}$ or GND		1.8		±5.0	μΛ
Bushold input minin	num drive	I _{I (HOLD)}	$V_{IN} = 0.36 V$		1.8	25	>	μΑ
hold current		il (HOLD)	V _{IN} = 1.26 V	(7/5)	1.8	-25	>	μΛ
Bushold input over-	drive current	I _{I (OD)}		(Note 1)	1.8	(4)	200	μА
to change state		11 (OD)		(Note 2)	1.8		-200	μΛ
3-state output OFF	state current	loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.8	_	±10.0	μА
Power-off leakage of	current	l _{OFF}	V _{OUT} = 0 to 3.6 V	· (7/	0	_	10.0	μА
Quiacaant aunnly a	ırront	laa	V _{IN} = V _{CC} or GND		1.8	_	20.0	^
Quiescent supply co	<u>CIIL</u>	Icc	V _{CC} ≤ V _{OUT} ≤ 3.6 V	(Note 3)	1.8	_	±20.0	μΑ

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

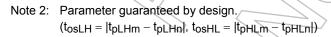




AC Characteristics (Ta = –40 to 85°C, input: $t_r = t_f$ = 2.0 ns, C_L = 30 pF, R_L = 500 Ω) (Note 1)

Characteristics	Symbol	Test Condition	1	Min	Max	Unit
Gharastenesse	Cymbol	Took Condition	V _{CC} (V)	141111	Wax	Offic
			1.8	125	_	
Maximum clock frequency	f _{max}	Figure 1, Figure 2	2.5 ± 0.2	200	_	MHz
			3.3 ± 0.3	250	_	
Dranagation delay time	4		1.8	1.5	6.0	
Propagation delay time (CK-Q)	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	1.0	4.8	ns
(CK-Q)	t _{pHL}	< ((3.3 ± 0.3	0.8	3.4	
	4		1.8	1.5	7.6	
3-state output enable time	t _{pZL}	Figure 1, Figure 3	2.5 ± 0.2	1.0	5.4	ns
	t _{pZH}		3.3 ± 0.3	0.8	3.9	
	4	4(>)	1.8	1(5	5.3	ns
3-state output disable time	t _{pLZ}	Figure 1, Figure 3	2.5 ± 0.2	1.0	4.4	
	t _{pHZ}	$((//5)^{\frac{1}{2}})$	3.3 ± 0.3	0.8	4.0	
Minimum pulse width	4		1.8	(3.0)	/ —	
(CK)	t _{w (H)}	Figure 1, Figure 2	2.5 ± 0.2	1.5	_	ns
(CK)	t _{w (L)}	4(>)	3.3 ± 0.3	1.5	_	
			1.8	2.5	_	
Minimum set-up time	ts	Figure 1, Figure 2	2.5 ± 0.2	1.5	_	ns
		4()	3.3 ± 0.3	1.5	_	
	/		1.8	1.0	_	
Minimum hold time	t _h	Figure 1) Figure 2	2.5 ± 0.2	1.0	_	ns
			3.3 ± 0.3	1.0	_	
			1.8	_	0.5	
Output to output skew	tosLH	(Note 2)	2.5 ± 0.2	_	0.5	ns
	tosHL		3.3 ± 0.3	_	0.5	

Note 1: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.





Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics		Symbol	Test Cor	ndition	V _{CC} (V)	Тур.	Unit
			$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	1.8	0.15	
Quiet output maximum dynamic	V_{OL}	V_{OLP}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	0.25	V
			V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	0.35	
			V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1,8	-0.15	
Quiet output minimum dynamic	V_{OL}	V_{OLV}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	-0.25	V
			V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	-0.35	
			V _{IH} = 1.8 V, V _{IL} = 0 V	(Nøte)	1.8	1.55	
Quiet output minimum dynamic	V_{OH}	V_{OHV}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	2.05	V
,			V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	2.65	

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}		1.8, 2.5, 3.3	6	pF
Output capacitance	CO		1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C_{PD}	f _{IN} = 10 MHz	(Note) 1.8, 2.5, 3.3	20	pF

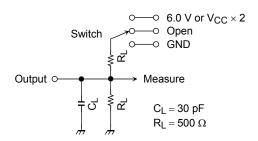
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$



AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

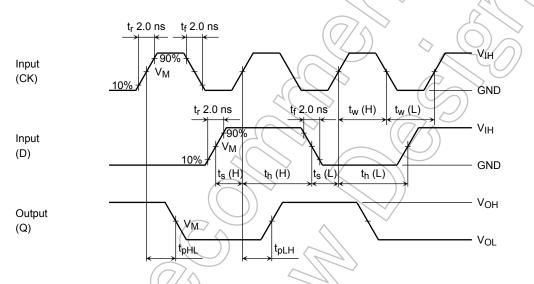


Figure 2 t_{pLH}, t_{pHL}, t_w, t_s, t_h

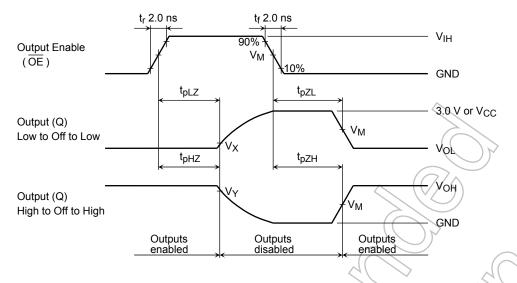
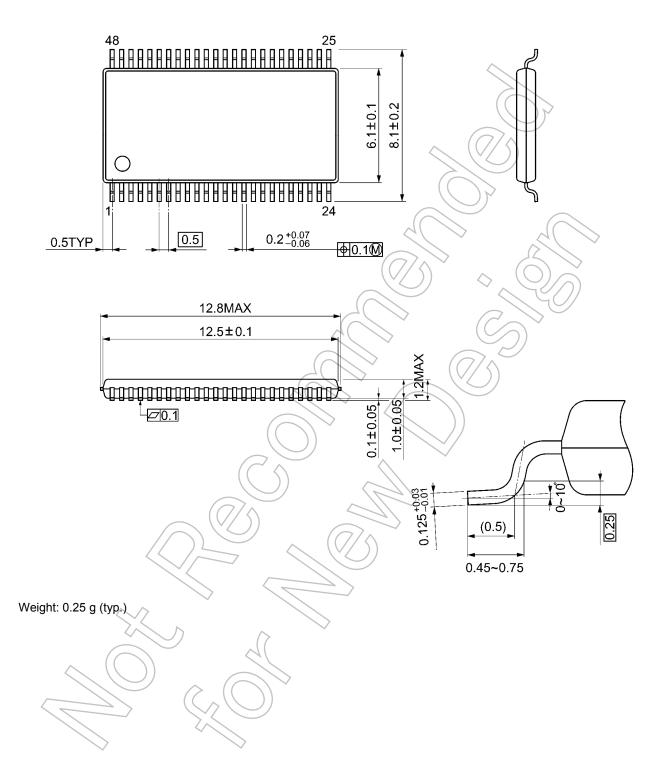


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Symbol		Vcc						
Symbol	$3.3\pm0.3~\textrm{V}$	2.5 ± 0.2 V	1.8 V					
V _{IH}	2.7 V	Vcc	v _{cc} (C					
V_{M}	1.5 V	V _{CC} /2	V _{CC} /2					
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V					
V_{Y}	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V					

Package Dimensions

TSSOP48-P-0061-0.50A Unit: mm



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